

### MCSO6E

High Temp Clock Oscillator 15 kHz - 60 MHz



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#### **APPLICATIONS**

Security / Safety Avionics / Aerospace Radio Communication Geothermal Equipment Remote Control / Telemetry Down Hole and Well Drilling

#### **DESCRIPTION**

The MCSO6E is a High Temperature, High Frequency SMD Oscillator that incorporates an integrated HCMOS circuit together with an XTAL. It operates under vacuum in a hermetically sealed ceramic package.

### **FEATURES**

Outstanding hermetic sealing with gold-tin preform. High stability and low aging guaranteed by hermetic sealing. Frequency stability guaranteed for 1000 h at T<sub>MAX</sub>. Very fast start-up.

Operates in fundamental mode.

High shock and vibration resistant.

100% Pb-free, RoHS-compliant.

## ELECTRICAL CHARACTERISTICS AT 25°C

Overall frequency stability over 1) temperature range	ΔF/F	≤ ±100 ≤ ±150 ≤ ±300 ≤ ±400	ppm
Supply voltage ±5% 3)	$V_{DD}$	2.5 / 3.3 / 5.0	V
Input current	I <sub>DD</sub>	See I <sub>DD</sub> table	
Output signal		HCMOS compatible	
F <sub>OUT</sub> duty cycle @ V <sub>DD</sub> /2 (min./max.)	$\delta_{\text{FOUT}}$	40 / 60	%
Rise & fall time For L version, $t_r / t_f \le 25$ ns ( $C_L = 15$ pF, 20% to 80% $V_{DD}$ )	t <sub>r</sub> / t <sub>f</sub>	≤ 7	ns
Output level V <sub>OL</sub> / V <sub>OH</sub>		< 0.4 / > V <sub>DD</sub> -0.5	V
Start-up time	t <sub>START</sub>	< 5	ms
Capacitive load min. / max. For L version, C <sub>L</sub> max. = 27 pF	C <sub>L</sub>	3 / 47	pF

- 1) Including adjustment at +25°C, long term aging 1000 h at  $T_{MAX}$ ,  $V_{DD}$  variations ±5% and  $C_{I}$  variations min. to max.
- 2) For the low consumption version (L), G version is only available as 5.0 V version and the G range is limited to +200°C
- 3) A 47 nF decoupling capacitor has to be connected between  $V_{DD}$  and GND

INPUT CURRENT: I<sub>DD</sub> (no load) (For L version, C<sub>L</sub> = 10 pF)

Frequency	32.768 kHz (L)	≤ 10 MHz	≤ 20 MHz	> 20 to 60 MHz
V <sub>DD</sub> = 2.5 V (W)	< 100 µA	< 2 mA	< 3 mA	< 15 mA
$V_{DD} = 3.3 \text{ V (V)}$	< 110 µA	< 4 mA	< 5 mA	< 20 mA
$V_{DD}$ = 5.0 V (Blank)	< 120 µA	< 6 mA	< 7 mA	< 30 mA

### STANDARD FREQUENCIES

Frequencies				
32.768 kHz	3.6864 MHz	4.0000 MHz	8.0000 MHz	10.0000 MHz
12.0000 MHz	12.8000 MHz	14.7456 MHz	16.0000 MHz	20.0000 MHz
24.0000 MHz				

L version: Other frequencies from 15 kHz to 100 kHz on request Standard version: Other frequencies from 100 kHz to 60 MHz on request

### **ENABLE/DISABLE E/D, OPTION 1**

Input level V <sub>IL</sub> / V <sub>IH</sub>		$< 0.3 V_{DD} / > 0.7 V_{DD}$	V
Reaction time, Standard version	t	< 1	μs
Reaction time, L version	t	< 5	ms

Pin 1 E/D	Pin 3 F <sub>OUT</sub>
V <sub>IH</sub> or open	Output enabled
V <sub>IL</sub>	Output disabled (Hi-Z)

No E/D function before  $V_{DD}$  is set.

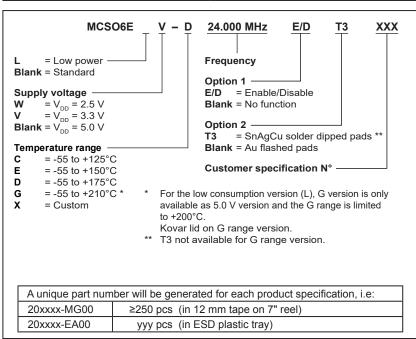
# ENVIRONMENTAL CHARACTERISTICS

		Conditions
	Storage temperature range	−65 to +125°C
(	Shock resistance (survival)	10000 g, 0.3 ms, ½ sine
[	Vibration resistance (survival)	80 g / 10 – 2000 Hz

TERMINATIONS AND PROCESSING, OPTION 2

Reflow per IPC/JEDEC J-STD-020C	260°C / 20 - 40 s	
Package	Ceramic	
Lid	Ceramic lid (Kovar lid on G range version)	
Terminations (Option 2) (T3 not available for G range)	SnAgCu solder dipped pads (T3)	
	Au flashed pads (Blank)	

### **ORDERING INFORMATION**



All specifications subject to change without notice.



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